NSN 5961-01-411-1961

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.146 inches
End Application:
Detector proc
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.9 reverse voltage, instantaneous
Terminal Type And Quantity:
2 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0